



## Input/Output Rail-to-Rail Low Power Operational Amplifier

- Rail-to-rail input common-mode voltage range
- Rail-to-rail output voltage swing
- Operating from 2.7V to 12V
- High-speed (3MHz, 1V/μs)
- Low consumption (0.9mA @ 3V)
- Supply voltage rejection ratio: 80dB
- Latch-up immunity
- Available in SOT23-5 micropackage

### Description

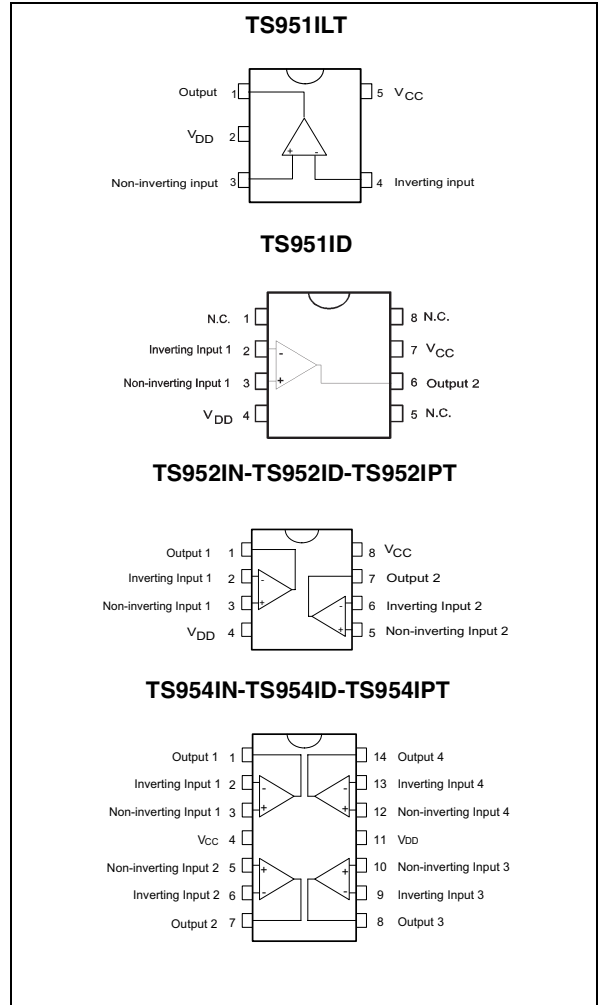
The TS95x family are rail-to-rail BiCMOS operational amplifiers optimized and fully specified for 3V and 5V operation.

The TS951 is housed in the space-saving 5 pins SOT23 package that makes it well suited for battery-powered systems. This micropackage simplifies the PC board design because of its ability to be placed in tight spaces (outside dimensions are: 2.8mm x 2.9mm)

### Applications

- Set-top boxes
- Laptop/notebook computers
- Transformer/line drivers
- Personal entertainments (CD players)
- Portable communication (cell phones, pagers)
- Instrumentation & sensing
- Digital to analog converter buffers
- Portable headphone speaker drivers

### Pin Connections (top view)



### Order Codes

Part Number	Temperature Range	Package	Packaging	Marking
TS951IN	-40°C, +125°C	DIP	Tube	
TS951ILT		SOT23-5L	Tape & Reel	K101
TS952IN		DIP	Tube	
TS952ID/IDT		SO	Tube or Tape & Reel	
TS952IPT		TSSOP (Thin Shrink Outline Package)	Tape & Reel	
TS954IN		DIP	Tube	
TS954ID/IDT		SO	Tube or Tape & Reel	
TS954IPT		TSSOP (Thin Shrink Outline Package)	Tape & Reel	

## 1 Absolute Maximum Ratings

**Table 1: Key parameters and their absolute maximum ratings**

Symbol	Parameter	Value	Unit
$V_{CC}$	Supply voltage <sup>1</sup>	14	V
$V_{id}$	Differential Input Voltage <sup>2</sup>	$\pm 1$	V
$V_{in}$	Input Voltage	$V_{DD}-0.3$ to $V_{CC}+0.3$	V
Tstg	Storage Temperature Range	-65 to +150	
$T_j$	Maximum Junction Temperature	150	°C
Rthja	Thermal Resistance Junction to Ambient <sup>3</sup>		°C/W
	SOT23-5	250	
	SO8	125	
	SO14	103	
	TSSOP8 TSSOP14	120 100	
ESD	Human Body Model	2	kV
ESD	HBM: Human Body Model <sup>4</sup>		
	TS951	1	kV
	TS952	2	
	TS954	3	
	MM: Machine Model <sup>5</sup>	100	V
	CDM: Charged Device Model	1.5	kV
	Latch-up Immunity	200	mA
	Lead Temperature (soldering, 10sec)	260	°C

1) All voltage values, except differential voltage are with respect to network ground terminal.

2) Differential voltages are the non-inverting input terminal with respect to the inverting input terminal. If  $V_{id} > \pm 1V$ , the maximum input current must not exceed  $\pm 1mA$ . In this case ( $V_{id} > \pm 1V$ ) an input serie resistor must be added to limit input current.

3) Short-circuits can cause excessive heating and destructive dissipation.

4) Human body model, 100pF discharged through a 1.5k $\Omega$  resistor into pin of device.

5) Machine model ESD, a 200pF cap is charged to the specified voltage, then discharged directly into the IC with no external series resistor (internal resistor < 5 $\Omega$ ), into pin to pin of device.

**Table 2: Operating Conditions**

Symbol	Parameter	Value	Unit
$V_{CC}$	Supply voltage	2.7 to 12	V
$V_{icm}$	Common Mode Input Voltage Range	$V_{DD}-0.2$ to $V_{CC}+0.1$	V
$T_{oper}$	Operating Free Air Temperature Range	-40 to +125	°C

## 2 Electrical Characteristics

**Table 3:  $V_{CC} = +3V$ ,  $V_{DD} = 0V$ ,  $R_L$  connected to  $V_{CC}/2$ ,  $T_{amb} = 25^\circ C$  (unless otherwise specified)**

Symbol	Parameter	Min.	Typ.	Max.	Unit
$V_{io}$	Input Offset Voltage $T_{min} \leq T_{amb} \leq T_{max}$			6 8	mV
$DV_{io}$	Input Offset Voltage Drift		2		$\mu V/^\circ C$
$I_{io}$	Input Offset Current $T_{min} \leq T_{amb} \leq T_{max}$		1	30 80	nA
$I_{ib}$	Input Bias Current $V_{icm} = V_{CC}/2$ $T_{min} \leq T_{amb} \leq T_{max}$		35	100 200	nA
$V_{icm}$	Common Mode Input Voltage Range	$V_{DD} - 0.2$ to $V_{CC} + 0.2V$			V
CMR	Common Mode Rejection Ratio	50	80		dB
SVR	Supply Voltage Rejection Ratio $V_{CC} = 2.7V$ to $3.3V$	60	80		dB
$A_{Vd}$	Large Signal Voltage Gain $V_o = 2V_{pk-pk}$ $R_L = 600\Omega$		80		dB
$V_{OH}$	High Level Output Voltage $R_L = 600\Omega$	2.8	2.9		V
$V_{OL}$	Low Level Output Voltage $R_L = 600\Omega$		80	250	mV
$I_{sc}$	Output Short Circuit Current	10			mA
$I_{CC}$	Supply Current (per Amplifier) No load, $V_{icm} = V_{CC}/2$		0.9	1.3	mA
GBP	Gain Bandwidth Product $R_L = 2k\Omega$		3		MHz
SR	Slew Rate		1		$V/\mu s$
$\phi_m$	Phase Margin at Unit Gain $R_L = 600\Omega$ , $C_L = 100pF$		60		Degrees
Gm	Gain Margin $R_L = 600\Omega$ , $C_L = 100pF$		10		dB
$e_n$	Equivalent Input Noise Voltage $f = 1kHz$		25		$\frac{nV}{\sqrt{Hz}}$
THD	Total Harmonic Distortion $V_{out} = 4V_{pk-pk}$ , $F = 10kHz$ , $A_v = 2$ , $R_L = 10k\Omega$		0.01		%

Table 4:  $V_{CC} = +5V$ ,  $V_{DD} = 0V$ ,  $R_L$  connected to  $V_{CC}/2$ ,  $T_{amb} = 25^\circ C$  (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
$V_{io}$	Input Offset Voltage $T_{min} \leq T_{amb} \leq T_{max}$			6 8	mV
$DV_{io}$	Input Offset Voltage Drift		2		$\mu V/^\circ C$
$I_{io}$	Input Offset Current $V_{icm} = V_{cc}/2$ $T_{min} \leq T_{amb} \leq T_{max}$		1	30 80	nA
$I_{ib}$	Input Bias Current $V_{icm} = V_{cc}/2$ $T_{min} \leq T_{amb} \leq T_{max}$		35	100 200	nA
$V_{icm}$	Common Mode Input Voltage Range	$V_{DD}^- - 0.2$ to $V_{CC}^+ + 0.2V$			V
CMR	Common Mode Rejection Ratio	50	80		dB
SVR	Supply Voltage Rejection Ratio $V_{cc} = 2.7V$ to $3.3V$	60	80		dB
$A_{vd}$	Large Signal Voltage Gain $V_o = 2V_{pk-pk}$ $R_L = 600\Omega$		86		dB
$V_{OH}$	High Level Output Voltage $R_L = 600\Omega$	4.7	4.8		V
$V_{OL}$	Low Level Output Voltage $R_L = 600\Omega$		80	300	mV
$I_{sc}$	Output Short Circuit Current	10			mA
$I_{cc}$	Supply Current (per Amplifier) No load, $V_{icm} = V_{cc}/2$		0.95	1.4	mA
GBP	Gain Bandwidth Product $R_L = 2k\Omega$		3		MHz
SR	Slew Rate		1		$V/\mu s$
$\phi_m$	Phase Margin at Unit Gain $R_L = 600\Omega$ , $C_L = 100pF$		60		Degrees
Gm	Gain Margin $R_L = 600\Omega$ , $C_L = 100pF$		10		dB
$e_n$	Equivalent Input Noise Voltage $f = 1kHz$		25		$\frac{nV}{\sqrt{Hz}}$
THD	Total Harmonic Distortion $V_{out} = 4V_{pk-pk}$ , $F = 10kHz$ , $A_v = 2$ , $R_L = 10k\Omega$		0.01		%

Figure 1: Supply current vs. supply voltage

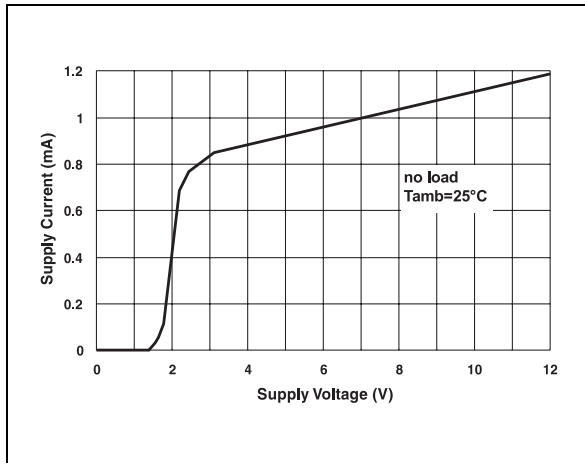


Figure 4: Supply current vs. temperature

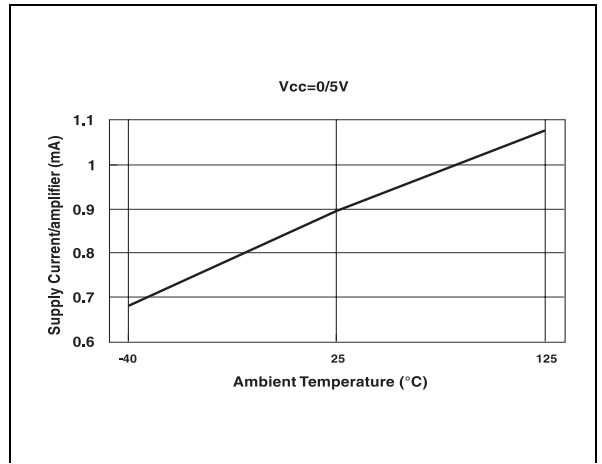


Figure 2: Output short circuit current vs. output voltage

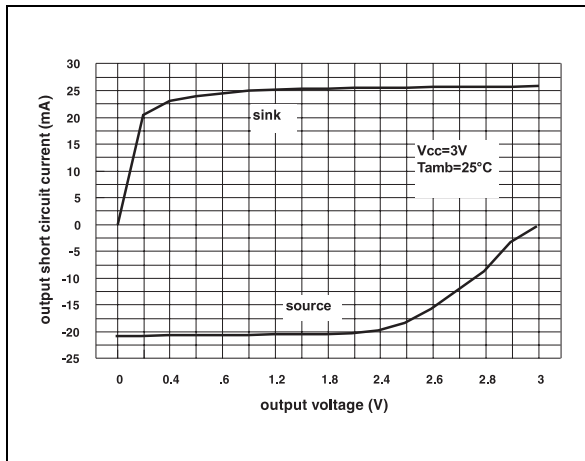


Figure 5: Output short circuit current vs. temperature

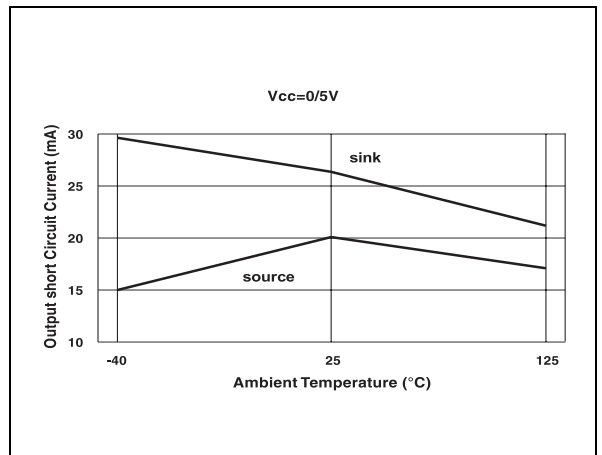


Figure 3: Voltage gain and phase vs. frequency

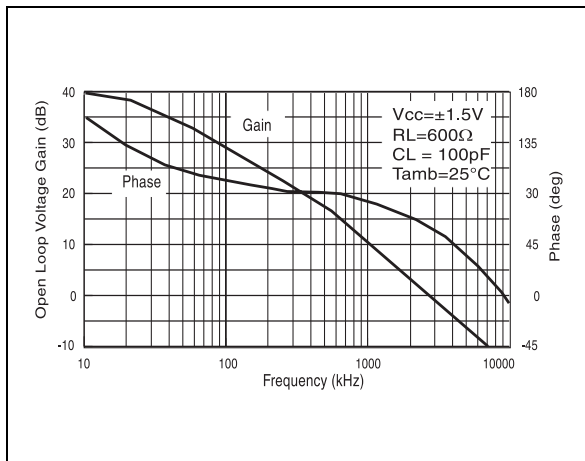


Figure 6: Slew rate vs. temperature

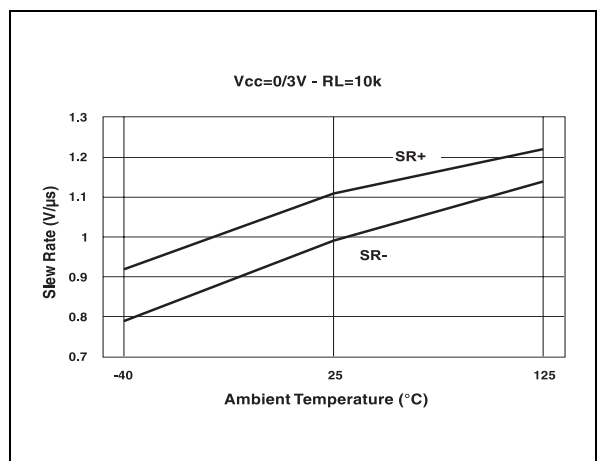


Figure 7: THD + noise vs. Vout

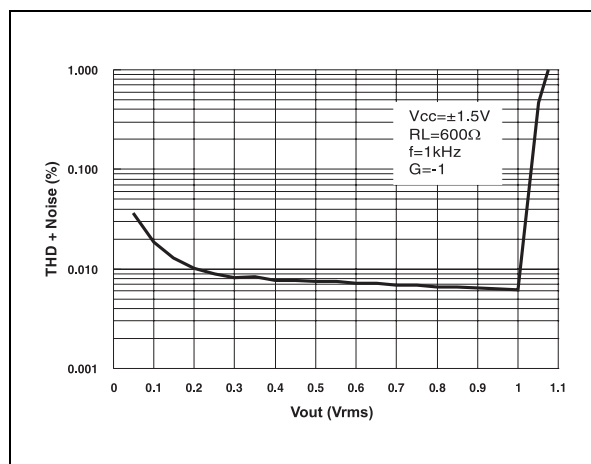


Figure 9: THD + noise vs. Vout

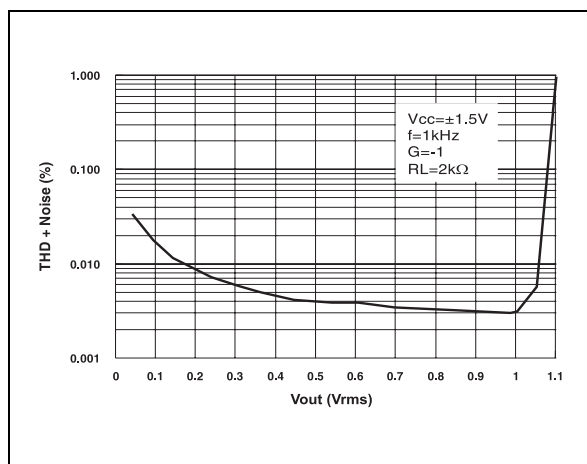


Figure 8: THD + noise vs. frequency

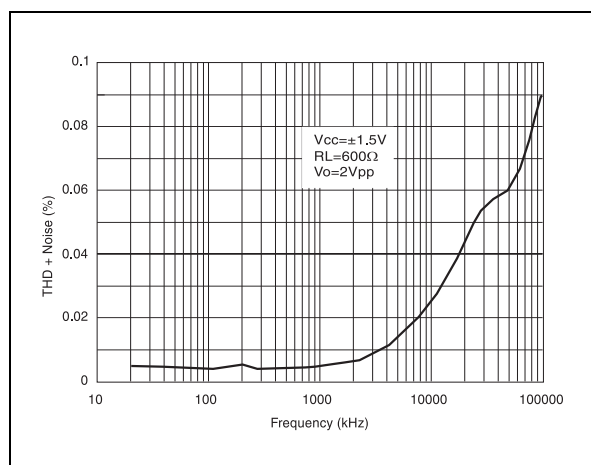
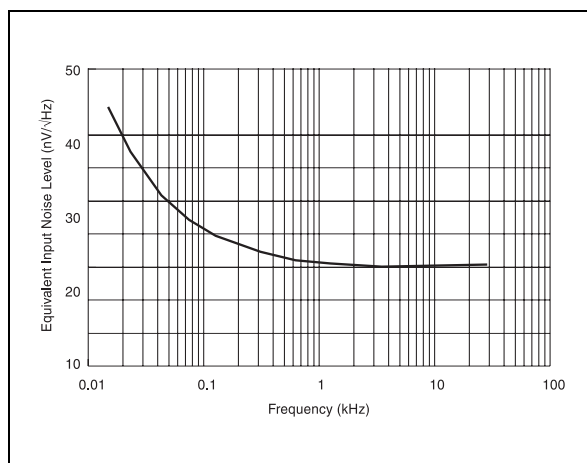


Figure 10: Equivalent input noise voltage vs. frequency

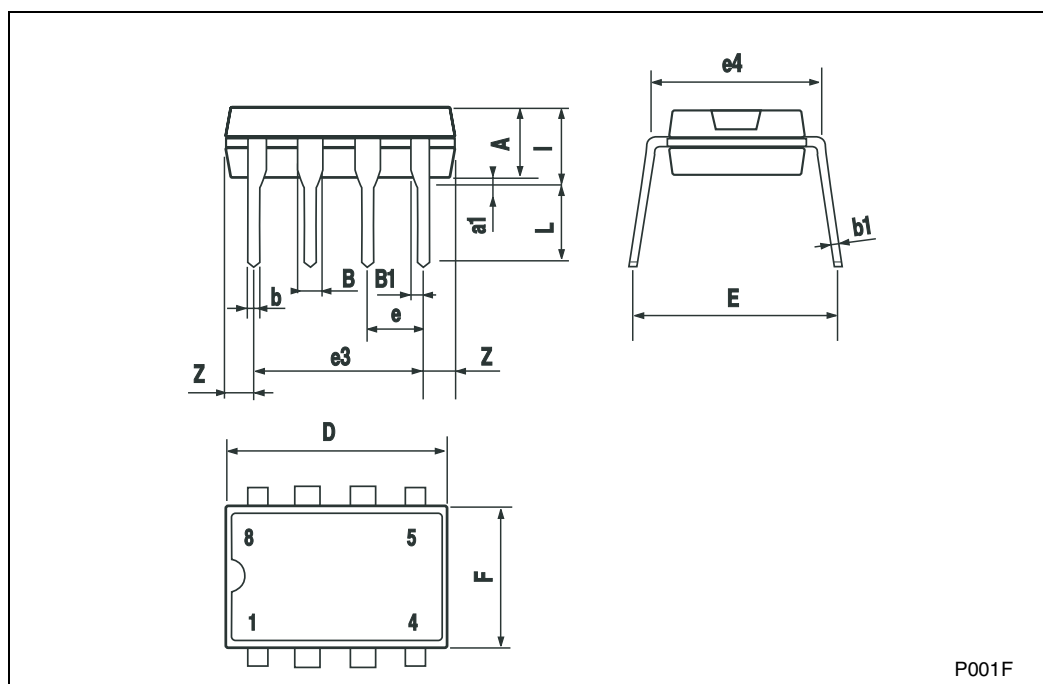


### 3 Package Mechanical Data

#### 3.1 DIP8 package

**Plastic DIP-8 MECHANICAL DATA**

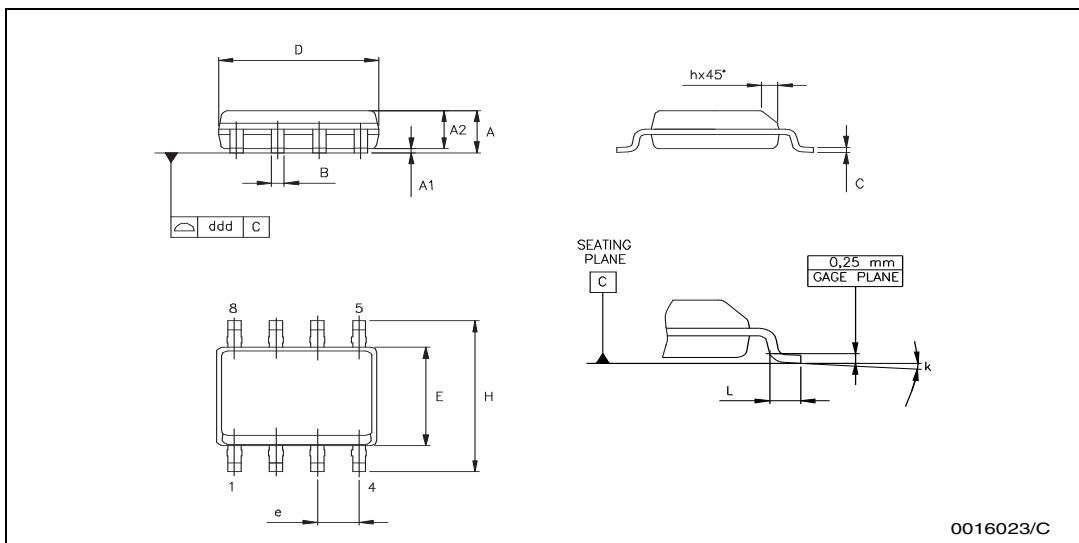
DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A		3.3			0.130	
a1	0.7			0.028		
B	1.39		1.65	0.055		0.065
B1	0.91		1.04	0.036		0.041
b		0.5			0.020	
b1	0.38		0.5	0.015		0.020
D			9.8			0.386
E		8.8			0.346	
e		2.54			0.100	
e3		7.62			0.300	
e4		7.62			0.300	
F			7.1			0.280
I			4.8			0.189
L		3.3			0.130	
Z	0.44		1.6	0.017		0.063



3.2 SO8 package

**SO-8 MECHANICAL DATA**

DIM.	mm.			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	1.35		1.75	0.053		0.069
A1	0.10		0.25	0.04		0.010
A2	1.10		1.65	0.043		0.065
B	0.33		0.51	0.013		0.020
C	0.19		0.25	0.007		0.010
D	4.80		5.00	0.189		0.197
E	3.80		4.00	0.150		0.157
e		1.27			0.050	
H	5.80		6.20	0.228		0.244
h	0.25		0.50	0.010		0.020
L	0.40		1.27	0.016		0.050
k	8° (max.)					
ddd			0.1			0.04



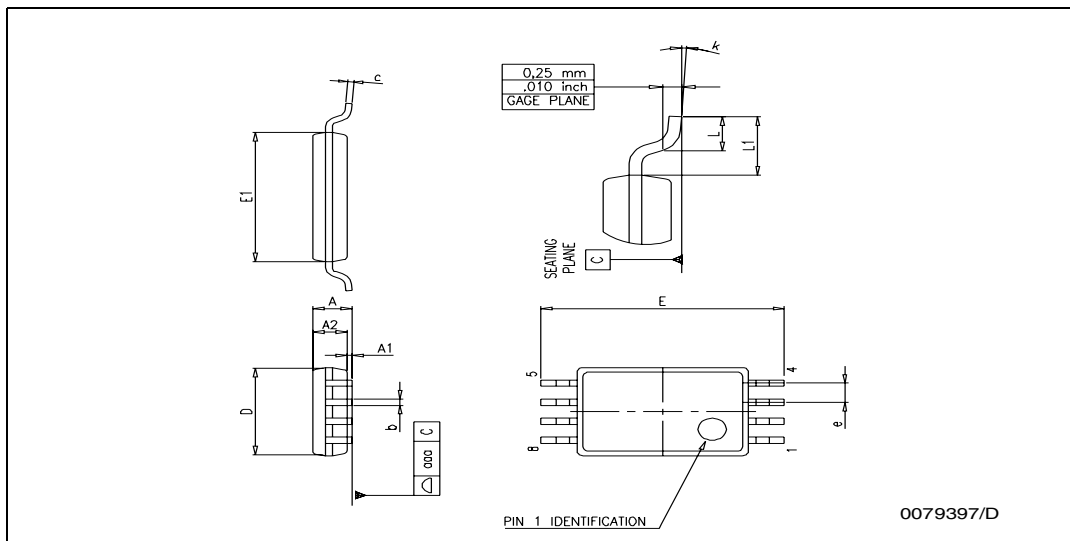
0016023/C



3.3 TSSOP8 package

**TSSOP8 MECHANICAL DATA**

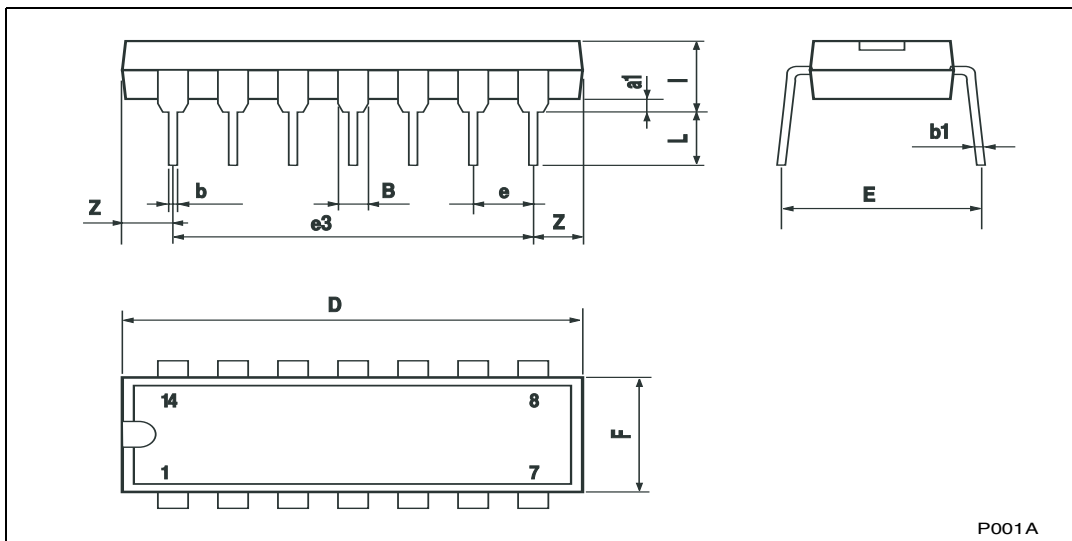
DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A			1.2			0.047
A1	0.05		0.15	0.002		0.006
A2	0.80	1.00	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.012
c	0.09		0.20	0.004		0.008
D	2.90	3.00	3.10	0.114	0.118	0.122
E	6.20	6.40	6.60	0.244	0.252	0.260
E1	4.30	4.40	4.50	0.169	0.173	0.177
e		0.65			0.0256	
K	0°		8°	0°		8°
L	0.45	0.60	0.75	0.018	0.024	0.030
L1		1			0.039	



3.4 DIP14 package

**Plastic DIP-14 MECHANICAL DATA**

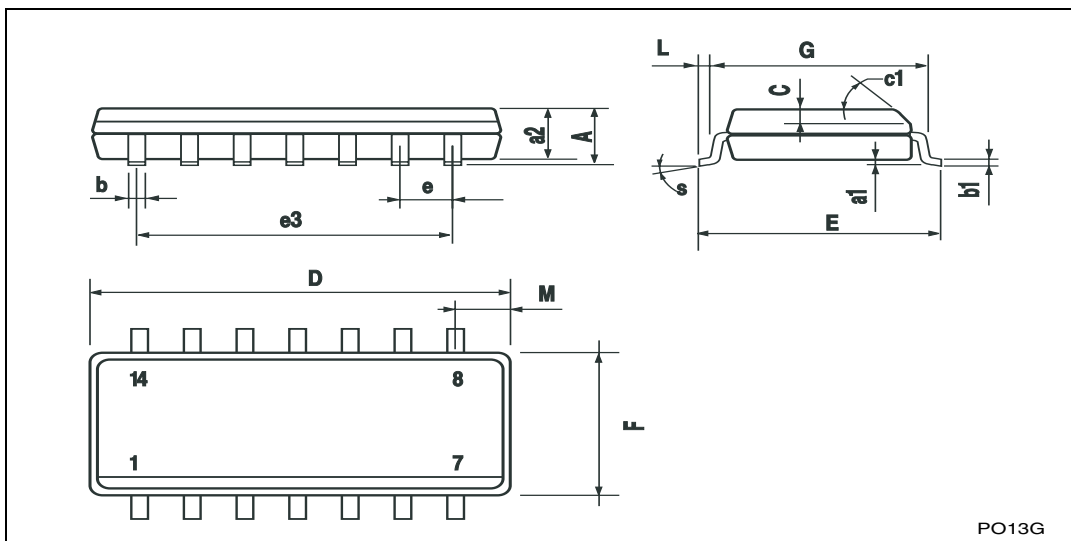
DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
B	1.39		1.65	0.055		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		15.24			0.600	
F			7.1			0.280
I			5.1			0.201
L		3.3			0.130	
Z	1.27		2.54	0.050		0.100



3.5 SO14 package

**SO-14 MECHANICAL DATA**

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A			1.75			0.068
a1	0.1		0.2	0.003		0.007
a2			1.65			0.064
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.019	
c1	45° (typ.)					
D	8.55		8.75	0.336		0.344
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		7.62			0.300	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
M			0.68			0.026
S	8° (max.)					

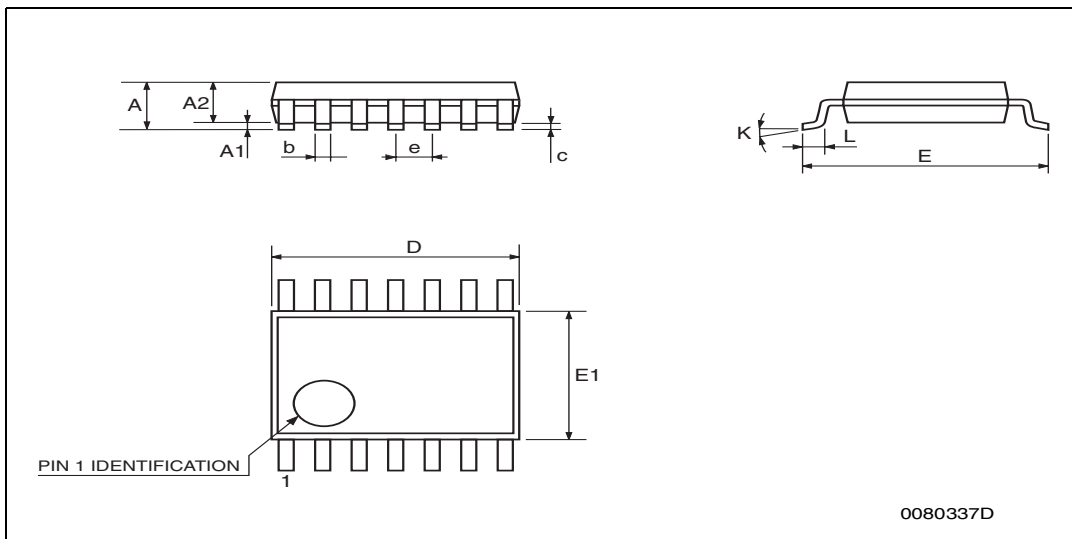


PO13G

3.6 TSSOP14 package

**TSSOP14 MECHANICAL DATA**

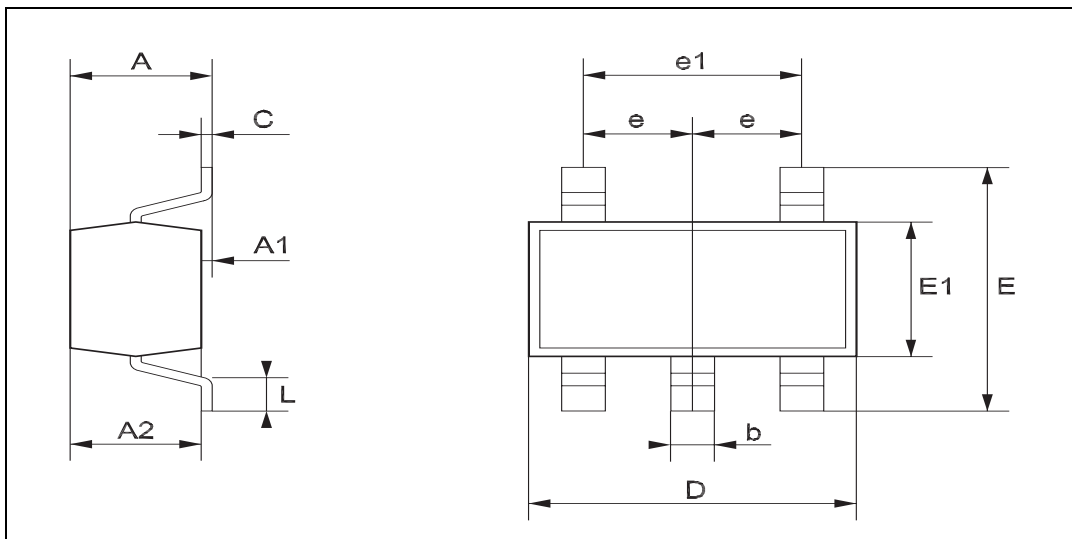
DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A			1.2			0.047
A1	0.05		0.15	0.002	0.004	0.006
A2	0.8	1	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.012
c	0.09		0.20	0.004		0.0089
D	4.9	5	5.1	0.193	0.197	0.201
E	6.2	6.4	6.6	0.244	0.252	0.260
E1	4.3	4.4	4.48	0.169	0.173	0.176
e		0.65 BSC			0.0256 BSC	
K	0°		8°	0°		8°
L	0.45	0.60	0.75	0.018	0.024	0.030



3.7 SOT23-5 package

**SOT23-5L MECHANICAL DATA**

DIM.	mm.			mils		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A	0.90		1.45	35.4		57.1
A1	0.00		0.15	0.0		5.9
A2	0.90		1.30	35.4		51.2
b	0.35		0.50	13.7		19.7
C	0.09		0.20	3.5		7.8
D	2.80		3.00	110.2		118.1
E	2.60		3.00	102.3		118.1
E1	1.50		1.75	59.0		68.8
e		0.95			37.4	
e1		1.9			74.8	
L	0.35		0.55	13.7		21.6



## 4 Summary of Changes

Date	Revision	Description of Changes
01 May 2001	1	First Release
01 Jan. 2005	2	Modifications on AMR <a href="#">Table 1 on page 2</a> (explanation of Vid and Vi limits, ESD MM and CDM values added, Rthja added)

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